## Power MOSFET

| PRODUCT SUMMARY |  |  |
| :--- | :--- | :--- |
| $\mathrm{V}_{\mathrm{DS}}(\mathrm{V})$ | 250 |  |
| $\mathrm{R}_{\mathrm{DS}(o n)}(\Omega)$ | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}$ | 0.14 |
| $\mathrm{Q}_{\mathrm{g}}(\mathrm{Max}).(\mathrm{nC})$ | 140 |  |
| $\mathrm{Q}_{\mathrm{gs}}(\mathrm{nC})$ | 24 |  |
| $\mathrm{Q}_{\mathrm{gd}}(\mathrm{nC})$ | 71 |  |
| Configuration | Single |  |



## FEATURES

- Dynamic dV/dt Rating
- Isolated Central Mounting Hole
- Fast Switching
- Ease of Paralleling
- Simple Drive Requirements
- Compliant to RoHS Directive 2002/95/EC


## DESCRIPTION

Third generation Power MOSFETs from Vishay provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness.
The TO-247AC package is preferred for commercial-industrial applications where higher power levels preclude the use of TO-220AB devices. The TO-247AC is similar but superior to the earlier TO-218 package because of its isolated mouting hole. It also provides greater creepage distance between pins to meet the requirements of most safety specifications.

## ORDERING INFORMATION

| Package | TO-247AC |
| :--- | :--- |
| Lead (Pb)-free | IRFP254PbF |
|  | SiHFP254-E3 |
| SnPb | IRFP254 |
|  | SiHFP254 |


| ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$, unless otherwise noted) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER |  |  | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage |  |  | $\mathrm{V}_{\mathrm{DS}}$ | 250 | V |
| Gate-Source Voltage |  |  | $\mathrm{V}_{\mathrm{GS}}$ | $\pm 20$ |  |
| Continuous Drain Current | $\mathrm{V}_{\mathrm{GS}}$ at 10 V | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | ID | 23 | A |
|  |  | $\mathrm{T}_{\mathrm{C}}=100^{\circ} \mathrm{C}$ |  | 15 |  |
| Pulsed Drain Current ${ }^{\text {a }}$ |  |  | $\mathrm{I}_{\mathrm{DM}}$ | 92 |  |
| Linear Derating Factor |  |  |  | 1.5 | W/ ${ }^{\circ} \mathrm{C}$ |
| Single Pulse Avalanche Energy ${ }^{\text {b }}$ |  |  | $\mathrm{E}_{\text {AS }}$ | 410 | mJ |
| Repetitive Avalanche Current ${ }^{\text {a }}$ |  |  | $\mathrm{I}_{\text {AR }}$ | 23 | A |
| Repetitive Avalanche Energy ${ }^{\text {a }}$ |  |  | $\mathrm{E}_{\text {AR }}$ | 19 | mJ |
| Maximum Power Dissipation | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | $\mathrm{P}_{\mathrm{D}}$ | 190 | W |
| Peak Diode Recovery dV/dt ${ }^{\text {c }}$ |  |  | dV/dt | 4.8 | V/ns |
| Operating Junction and Storage Temperature Range |  |  | $\mathrm{T}_{\mathrm{J},} \mathrm{T}_{\text {stg }}$ | - 55 to + 150 | ${ }^{\circ} \mathrm{C}$ |
| Soldering Recommendations (Peak Temperature) | for 10 s |  |  | $300{ }^{\text {d }}$ |  |
| Mounting Torque | 6-32 or M3 screw |  |  | 10 | $\mathrm{lbf} \cdot \mathrm{in}$ |
|  |  |  |  | 1.1 | $N \cdot m$ |

## Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11).
b. $\mathrm{V}_{\mathrm{DD}}=50 \mathrm{~V}$, starting $\mathrm{T}_{J}=25^{\circ} \mathrm{C}, \mathrm{L}=1.2 \mathrm{mH}, \mathrm{R}_{\mathrm{g}}=25 \Omega, \mathrm{I}_{\mathrm{AS}}=23 \mathrm{~A}$ (see fig. 12).
c. $\mathrm{I}_{\mathrm{SD}} \leq 23 \mathrm{~A}, \mathrm{dl} / \mathrm{dt} \leq 180 \mathrm{~A} / \mu \mathrm{s}, \mathrm{V}_{\mathrm{DD}} \leq \mathrm{V}_{\mathrm{DS}}, \mathrm{T}_{\mathrm{J}} \leq 150^{\circ} \mathrm{C}$.
d. 1.6 mm from case.

* Pb containing terminations are not RoHS compliant, exemptions may apply


## Vishay Siliconix

| THERMAL RESISTANCE RATINGS |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TYP. | MAX. | UNIT |
| Maximum Junction-to-Ambient | $\mathrm{R}_{\mathrm{thJA}}$ | - | 40 |  |
| Case-to-Sink, Flat, Greased Surface | $\mathrm{R}_{\mathrm{thCs}}$ | 0.24 | - |  |
| Maximum Junction-to-Case (Drain) | $\mathrm{R}_{\mathrm{thJC}}$ | - | 0.65 |  |



## Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11).
b. Pulse width $\leq 300 \mu$ s; duty cycle $\leq 2 \%$.

TYPICAL CHARACTERISTICS $\left(25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


Fig. 1 - Typical Output Characteristics, $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$


Fig. 2 - Typical Output Characteristics, $\mathrm{T}_{\mathrm{C}}=150^{\circ} \mathrm{C}$


Fig. 3-Typical Transfer Characteristics


Fig. 4 - Normalized On-Resistance vs. Temperature

Vishay Siliconix


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage


Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage


Fig. 7 - Typical Source-Drain Diode Forward Voltage


Fig. 8 - Maximum Safe Operating Area


Fig. 9 - Maximum Drain Current vs. Case Temperature


Fig. 10a - Switching Time Test Circuit


Fig. 10b - Switching Time Waveforms


Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case


Fig. 12a - Unclamped Inductive Test Circuit


Fig. 12b - Unclamped Inductive Waveforms


Fig. 12c - Maximum Avalanche Energy vs. Drain Current


Fig. 13a - Basic Gate Charge Waveform


Fig. 13b - Gate Charge Test Circuit


Fig. 14 - For N -Channel

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?91214.

## TO-247AC (High Voltage)

## VERSION 1: FACILITY CODE = 9



Section C--C, D--D, E--E

|  | MILLIMETERS |  |  |
| :---: | :---: | :---: | :---: |
| DIM. | MIN. | MAX. | NOTES |
| A | 4.83 | 5.21 |  |
| A1 | 2.29 | 2.55 |  |
| A2 | 1.50 | 2.49 |  |
| b | 1.12 | 1.33 |  |
| b1 | 1.12 | 1.28 |  |
| b2 | 1.91 | 2.39 | 6 |
| b3 | 1.91 | 2.34 |  |
| b4 | 2.87 | 3.22 | 6,8 |
| b5 | 2.87 | 3.18 |  |
| c | 0.55 | 0.69 | 6 |
| c1 | 0.55 | 0.65 |  |
| D | 20.40 | 20.70 | 4 |


|  | MILLIMETERS |  |  |
| :---: | :---: | :---: | :---: |
| DIM. | MIN. | MAX. | NOTES |
| D1 | 16.25 | 16.85 | 5 |
| D2 | 0.56 | 0.76 |  |
| E | 15.50 | 15.87 | 4 |
| E1 | 13.46 | 14.16 | 5 |
| E2 | 4.52 | 5.49 | 3 |
| e | 5.44 BSC |  |  |
| L | 14.90 | 15.40 |  |
| L1 | 3.96 | 4.16 | 6 |
| $\varnothing$ P | 3.56 | 3.65 | 7 |
| $\varnothing$ P1 | 7.19 ref. |  |  |
| Q | 5.31 | 5.69 |  |
| S | 5.54 | 5.74 |  |

## Notes

(1) Package reference: JEDEC TO247, variation AC
(2) All dimensions are in mm
(3) Slot required, notch may be rounded
(4) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm per side. These dimensions are measured at the outermost extremes of the plastic body
(5) Thermal pad contour optional with dimensions D1 and E1
(6) Lead finish uncontrolled in L1
(7) $\varnothing \mathrm{P}$ to have a maximum draft angle of $1.5^{\circ}$ to the top of the part with a maximum hole diameter of 3.91 mm
(8) Dimension b2 and b4 does not include dambar protrusion. Allowable dambar protrusion shall be 0.1 mm total in excess of b2 and b4 dimension at maximum material condition

## VERSION 2: FACILITY CODE $=\mathbf{Y}$



|  | MILLIMETERS |  |  |
| :---: | :---: | :---: | :---: |
| DIM. | MIN. | MAX. | NOTES |
| A | 4.58 | 5.31 |  |
| A1 | 2.21 | 2.59 |  |
| A2 | 1.17 | 2.49 |  |
| b | 0.99 | 1.40 |  |
| b1 | 0.99 | 1.35 |  |
| b2 | 1.53 | 2.39 |  |
| b3 | 1.65 | 2.37 |  |
| b4 | 2.42 | 3.43 |  |
| b5 | 2.59 | 3.38 |  |
| c | 0.38 | 0.86 |  |
| c1 | 0.38 | 0.76 |  |
| D | 19.71 | 20.82 |  |
| D1 | 13.08 | - |  |
| ECN: E19-0014 Rev. E, 25 | 2019 |  |  |

## ECN: E19-0614-Rev. E, 25-Nov-2019

DWG: 5971

## Notes

${ }^{(1)}$ Dimensioning and tolerancing per ASME Y14.5M-1994
(2) Contour of slot optional
${ }^{(3)}$ Dimension D and E do not include mold flash. Mold flash shall not exceed $0.127 \mathrm{~mm}\left(0.005{ }^{\prime \prime}\right)$ per side. These dimensions are measured at the outermost extremes of the plastic body
${ }^{(4)}$ Thermal pad contour optional with dimensions D1 and E1
${ }^{(5)}$ Lead finish uncontrolled in L1
${ }^{(6)} \varnothing \mathrm{P}$ to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of $3.91 \mathrm{~mm}(0.154$ ")
(7) Outline conforms to JEDEC outline TO-247 with exception of dimension c
(8) Xian and Mingxin actually photo

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

